

Vector Signal Generator R&S SMV03

Vector modulation in the analog class

- Frequency range 9 kHz to 3.3 GHz
- I/Q modulator (100 MHz RF bandwidth) with excellent vector accuracy (f >500 MHz to 3 GHz)
- ◆ SSB phase noise —128 dBc (1 Hz)
- ◆ Setting times <10 ms
- ◆ High level accuracy <0.5 dB</p>
- High reliability through electronic attenuator
- Digital frequency and level sweep
- AM/FM/φM
- Optional pulse modulator with integrated pulse generator
- 3-year calibration cycle



The allrounder

The Vector Signal Generator R&S SMV 03 is based on the successful analog Signal Generator R&S SML 03 and so features the same excellent technical characteristics. It comprises an additional broadband I/Q modulator which is able to generate any digital signal in conjunction with an external I/Q source. The R&S SMV 03 is, therefore, a way of entering the wide field of automatic test systems as well as gaining access to applications like R&D and service. When used together with the R&S AMIQ and R&S WinIQSIM™, the R&S SMV 03 can generate digital signals that meet any requirement.

RF characteristics

- Frequency range from 9 kHz to
 3.3 GHz with 0.1 Hz resolution
- High output level of +13 dBm with a deviation <0.5 dB
- Interruption-free level setting by electronic attenuator
- High spectral purity (<-122 dBc (1 Hz) at f = 1 GHz and 20 kHz carrier offset)
- Frequency and level setting time
 <10 ms

Vector modulation

- Wide I/O bandwidth of >50 MHz (3 dB), 100 MHz RF bandwidth for f >500 MHz to 3 GHz
- High vector accuracy

Analog modulation

- AM/FM/φM as standard
- Simultaneous AM, FM/φM, pulse and vector modulation
- Optional pulse modulator with integrated pulse generator (R&S SML-B3)

Dimensions

- Compact size427 mm x 88 mm x 450 mm
- ◆ Low weight <9.5 kg

Low cost of ownership

- 3-year calibration cycle
- Electronic attenuator for wear-free operation
- Service-friendly (continuous selftest, access to internal test points)



Applications

Production: fast, accurate, reliable

Versatility

The R&S SMV03 generates all kinds of I/Q-modulated signals using the integrated vector modulator. Thanks to its wide I/Q bandwidth of 50 MHz, the R&S SMV03 is also optimally suited for applications using high data rates such as WLAN standards. Signals to digital stan-dards can be easily generated in conjunction with an external I/Q source like the Modulation Generator R&S AMIQ (PD 0757.3970) and the associated R&S WinIQSIM™ simulation software (PD 0757.6940).

The R&S SMV03 therefore optimally meets production environment requirements.

Dimensions

The compact size (only 2 HU) makes the R&S SMV03 ideal for use in production where space is often limited.

Speed

Speed is essential — especially in production. And this is exactly where the R&S SMV03 shows what it can do with a frequency and level setting time of <10 ms.

Accuracy

Any measurement uncertainty has two components: the uncertainty due to the measuring instrument and that due to the rest of the test setup. The lower the level uncertainty of the vector signal generator, the greater the test setup tolerance that may be allowed. If greater tolerances can be allowed for the DUT because of the small level error of the R&S SMV03, production rejects can be markedly reduced — an advantage that pays off immediately.

Reliability

A signal generator used in production must feature high reliability. The R&S SMV03 meets this requirement, for example, through the use of a completely wear-free electronic attenuator.

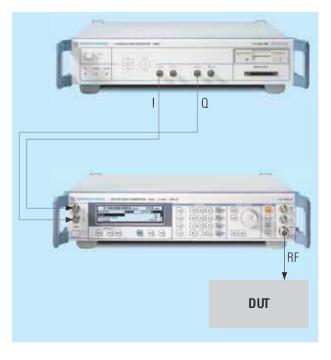
Output level

In production test systems, the signal is routed to the DUT via switches and cables which introduce losses. This can be compensated for by the high output power of the R&S SMV03.

Example: component test

◆ Tests using digital signals are becoming increasingly important for checking the functions of individual components — especially at the component production stage. In this environment, the R&S SMV03's I/Q modulator shows what it can do. Thanks to its wide signal bandwidth of 50 MHz, it can generate a great variety of digital signals when an external I/Q source is used.

- ◆ To obtain reliable information on component quality, high level accuracy and high output level repeatability are essential. The R&S SMV03 fully meets these requirements thanks to a maximum level uncertainty of <0.5 dB (at levels >−120 dBm) and high reproducibility.
- Extremely short frequency and level setting times (<10 ms) allow fast measurements and make the R&S SMV 03 the ideal generator for production testing.
- Overshoots that occur when the level is changed may damage or even destroy the DUT. This cannot happen with the R&S SMV03 as no overshoots are produced.



Applications

Lab and R&D: versatile

Versatile modulation modes

Particularly in research, a great variety of digital signals are used in the development of new systems, which are not always covered by a standard. Thanks to its very wideband I/Q modulator, the R&S SMV03 can handle universal tasks of this kind.

In conjunction with the optional Pulse Modulator R&S SML-B3, the vector signal generator can also handle all types of analog modulation. AM, FM/ ϕ M and pulse modulation can be used simultaneously as can vector modulation, FM/ ϕ M and pulse modulation.

High spectral purity

Thanks to its low phase noise, the R&S SMV03 is ideally suited to replace LOs.

High and accurate output level

The high level accuracy of the Vector Signal Generator R&S SMV03 is a prerequisite for highly accurate measurements on sensitive analog and digital receivers. Its high output level makes the R&S SMV03 an ideal source for driving high-level mixers.

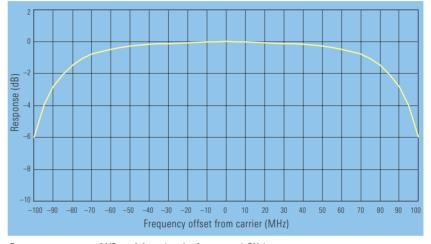
Excellent modulation characteristics

As the R&S SMV03 provides high-linearity FM, it can be used as a precise VCO.

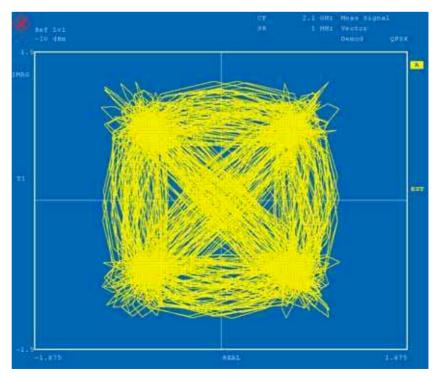
Example: receiver measurements

Sensitivity measurements require a signal generator with high level accuracy. High accuracy is even more critical at low output levels. Thanks to its sophisticated calibration methods, the R&S SMV03 features high level accuracy (uncertainty <0.5 dB at levels >-120 dBm).

- Minimal spurious, minimal broadband noise and, above all, excellent SSB phase noise are prerequisites for using the R&S SMV 03 as an interference source.
 - With an SSB phase noise of typ. -128 dBc/Hz (at f = 1 GHz, Δ f = 20 kHz), spurious suppression of typ.
- -76 dBc and broadband noise of typ.
 -150 dBc (1 Hz), the R&S SMV03 meets even the most exacting requirements.
- The mechanical design of the R&S SMV 03 ensures excellent RF shielding of its casing. This is particularly important for measurements on highly sensitive receivers with built-in antenna.



Frequency response of I/Q modulator (carrier frequency 1 GHz)



Vector diagram of QPSK signals

Servicing: robust, compact, lightweight

Mobility

The R&S SMV03 is lightweight (<9.5 kg) and compact and therefore very easy to transport.

Flexible control

In service environments, an IEC/IEEE bus interface is not always available to control the generator. This is not a problem as the R&S SMV03 can also be controlled via a standard RS-232-C interface.

Protection against overvoltage

The integrated overvoltage protection of the RF output protects the R&S SMV03 against very high external voltages such as may occur during transceiver measurements.

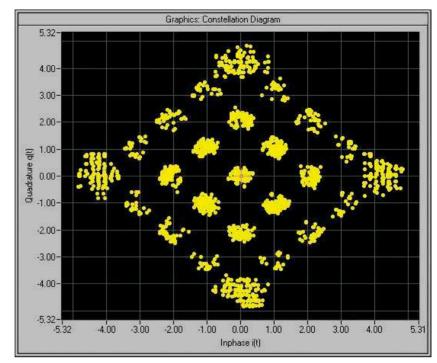
EMS measurements

Interruption-free level setting without overshoots

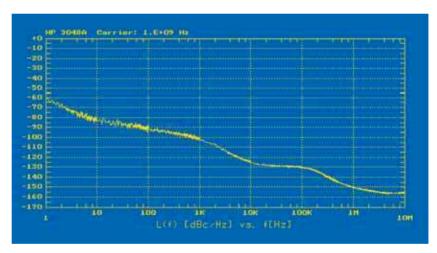
EMS measurements require interruptionfree level setting which should also be overshoot-free. The R&S SMV 03 does not produce any overshoots — even at setting times <10 ms. Furthermore, it has a wide dynamic range of typ. 30 dB over which level adjustment is interruption-free.

Wide frequency range

The R&S SMV03 features a lower frequency limit of 9 kHz as standard and so fully covers the frequency range required for EMC measurements.



Constellation diagram of WCDMA signal in 3GPP TDD mode



Typical SSB phase noise at 1 GHz (with OCXO option R&S SML-B1)



Module test with R&S SMV03, R&S AMIQ and Spectrum Analyzer R&S FSP

Reference source

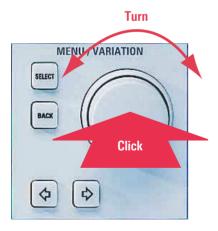
The R&S SMV03 allows selection of the mode of frequency generation. In the extended divider range mode, the RF signal is generated by frequency division. The excellent values obtained in this mode for SSB phase noise are comparable to those from the high-grade crystal oscillators normally used as reference sources from 10 MHz to 30 MHz.

Compared to crystal oscillators, the R&S SMV03 has the following benefits:

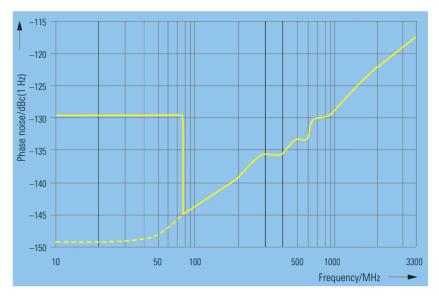
- Frequency can be set in 0.1 Hz steps and synchronized to an external reference
- All functions can be remotely controlled via the IEC/IEEE bus or serial interface

EasyWheel

- One-hand operation with EasyWheel
- All settings simple and self-explanatory
- High-contrast LCD
- User-assignable menu keys
- Online help including IEC/IEEE bus commands



Simply select the desired menu with the spinwheel and click the button to open the submenu



Typical SSB phase noise versus carrier frequency (carrier offset 20 kHz); dashed line: extended divider range mode

Offset from carrier	SSB phase noise, typical values
1 Hz	-95 dB
10 Hz	−120 dB
100 Hz	−130 dB
1 kHz	−138 dB
10 kHz	−148 dB

SSB phase noise at 9.5 MHz output frequency, extended divider range activated, 1 Hz measurement bandwidth





Specifications

Specifications apply under the following conditions: 30 minutes warmup time at ambient temperature, specified environmental conditions met, calibration cycle adhered to, and total calibration performed. Data designated "nominal" are design parameters and are not tested. Data designated "overrange" are not warranted.

Frequency

1 1 0 quotio,	
R&S SMV03 I/Q modulation off I/Q modulation on	9 kHz to 3.3 GHz 5 MHz to 3.3 GHz
Resolution	0.1 Hz
Setting time (for an offset of $<1x10^{-7}$ or <90 Hz for f \leq 76 MHz) after IEC/IEEE	
bus delimiter	
I/Q modulation off I/Q modulation on	<10 ms <12 ms

Reference frequency

	Standard	Option R&S SML-B1
Aging (after 30 days of operation)	<1 x 10 ⁻⁶ /year	<1 x 10 ⁻⁷ /year <5 x 10 ⁻¹⁰ /day
Temperature effect (0°C to 55°C)	$<1 \times 10^{-6}$	<2 x 10 ⁻⁸
Output for internal reference Frequency Output voltage, V rms, sinewave Source impedance	10 MHz >0.5 V into 50 Ω 50 Ω)
Input for external reference Frequency Permissible frequency drift Input voltage, V rms, sinewave Input impedance	10 MHz 5 x 10 ⁻⁶ 0.5 V to 2 V into 50 Ω	50 Ω
Spectral purity		

<-30 dBc at levels ≤+8 dBm

Spectral purity

Subharmonics

Spurious signals Harmonics¹⁾ (for f >100 kHz)

f ≤1.1 GHz	-
f >1.1 GHz	<-50 dBc
Nonharmonics	
(carrier offset >10 kHz)	
f ≤1.1 GHz	<-70 dBc
f >1.1 GHz to 2.2 GHz	<-64 dBc
f >2.2 GHz to 3.3 GHz	<-58 dBc
Broadband noise ^{2) 3)} ($f = 1$ GHz,	
carrier offset >2 MHz, 1 Hz bandwidth)	<-135 dBc, -140 dBc typ.
SSB phase noise (f = 1 GHz,	
20 kHz carrier offset, 1 Hz bandwidth)	<-122 dBc, -128 dBc typ.
Spurious FM, rms (f = 1 GHz)	
0.3 kHz to 3 kHz	<4 Hz, 1 Hz typ.
0.03 kHz to 20 kHz	<10 Hz, 3 Hz typ.
Spurious AM, rms	
0.03 kHz to 20 kHz	<0.02%
Level	

20101	
Range	$-140 \text{ dBm to } +13 \text{ dBm }^{2) 4}$ (overrange +19 dBm)
Resolution	0.1 dB
Level accuracy $^{2/3}$ (level >—120 dBm) 100 kHz to \leq 2 GHz f >2 GHz	<0.5 dB <0.9 dB
Frequency response at 0 dBm ^{2) 3)} 100 kHz to ≤2 GHz f >2 GHz	<0.7 dB <1.0 dB

Characteristic impedance	50 Ω
SWR 100 kHz to 1.5 GHz f >1.5 GHz	1.6 2.3
Setting time (IEC/IEEE bus), f >100 kHz	<10 ms, 5 ms typ.
Interruption-free level setting ⁵⁾ (for f >100 kHz) I/Q modulation off I/Q modulation on	20 dB, overrange 30 dB 15 dB, overrange 20 dB
Overvoltage protection	safeguards unit against externally applied RF power and DC voltage (50 Ω source)
Max. permissible RF power $f \le 2.2 \text{ GHz}$ $f > 2.2 \text{ GHz}$	50 W 25 W
Max. permissible DC voltage	35 V
Vector modulation	

Vector modulation

Additional level inaccuracy in case of vector modulation (ALC OFF), referred to CW mode	<0.3 dB
Operating mode	external DC
I and Q modulation inputs Input impedance SWR (DC to 30 MHz) Input voltage for full-scale level	50Ω <1.2 $\sqrt{1^2 + \Omega^2} = 0.5V$ (1 V EMF with 50 Ω source)
01	

Static error vector ⁶⁾ ,		
Level <+8 dBm		
Rms value		
f <2.6 GHz	<0.5%	
f > 2.6 GHz to $f = 3$ GHz	<0.7%	
Peak value		
f < 2.6 GHz	<1%	
f > 2.6 GHz to f = 3 GHz	<1.4%	
M III		

ivioudiation nequency response	
f >500 MHz to 3 GHz	
DC to 5 MHz	<0.4 dB
DC to 50 MHz	<3 dB
$f < 500 \text{ MHz}$ and $f > 3 \text{ GHz}^{7)}$	
DC to 5 MHz	~0.4 dR

DC to 30 MHz <3 dB

Residual carrier at 0 V input voltage < 45 dBc (at f=5 MHz to 3 GHz) referred to max. input voltage

I/Q imbalance Carrier leakage Setting range Resolution l≠0

0% to 50% 0.5%

-12% to +12%Setting range Resolution 0.1% Quadrature offset Setting range -10° to $+10^{\circ}$ Resolution 0.1°

Adjacent-channel leakage ratio (ACLR) WCDMA 3GPP FDD (f = 2.14 GHz)

Test model 1 (64 DPCHs) Offset 5 MHz nom. >60 dB, 62 dB typ. nom. >64 dB, 66 dB typ. Offset 10 MHz

Internal modulation generator

Frequency (Resolution	0	0.1 Hz to 1 MHz 0.1 Hz
Frequency a	accuracy	as for reference frequency + 2.4 x 10 ⁻³ Hz

Frequency response (up to 500 kHz, level >100 mV)	<0.5 dB
THD (up to 100 kHz, level 4 V, $\rm R_{L} = 600~\Omega)$	<0.1%
Open-circuit voltage V _p (LF connector) Resolution Setting accuracy (at 1 kHz)	1 mV to 4 V 1 mV 1 mV 1 % of V_{o} + 1 mV
Output impedance	approx. 10 Ω
Frequency setting time (after reception	арриол. 10 22
of last IEC/IEEE bus character)	<10 ms
Simultaneous modulation	AM, FM/ ϕM and pulse modulation or vector modulation, FM/ ϕM and pulse modulation
Amplitude modulation ⁸⁾	
Operating modes	internal, external AC/DC, internal/external two-tone
Modulation depth	0% to 100% settable modulation depth continuously decreasing between +7 dBm and +13 dBm ⁹⁾ while adhering to AM specifications; a status message is output when the modulation depth is too high
Resolution	0.1%
Setting accuracy at 1 kHz (m <80%) ¹⁰⁾	<4% of reading +1%
AM distortion at 1 kHz $m = 30\%$ $m = 80\%$	<1% <2%
Modulation frequency range (<3 dB)	DC/10 Hz to 50 kHz
Incidental φM at AM (30%), AF = 1 kHz	<0.2 rad
Modulation input EXT Input impedance Input voltage V _p for set modulation depth	>100 kΩ
Frequency modulation	
Operating modes	internal, external AC/DC, internal/external two-tone
Frequency deviation 9 kHz to 76 MHz > 76 MHz to 151.3125 MHz > 151.3125 MHz to 302.625 MHz > 302.625 MHz to 605.25 MHz > 605.25 MHz to 1.2105 GHz > 1.2105 GHz to 1.818 GHz > 1.818 GHz to 2.655 GHz > 2.655 GHz to 3.300 GHz	0 Hz to 1 MHz 0 Hz to 125 kHz 0 Hz to 250 kHz 0 Hz to 500 kHz 0 Hz to 1 MHz 0 Hz to 2 MHz 0 Hz to 3 MHz 0 Hz to 4 MHz
Resolution	<1% of set deviation, minimum 10 Hz
Setting accuracy (at AF = 1 kHz)	<4% of reading + 20 Hz
FM distortion (at AF = 1 kHz and 50% of max. deviation)	<0.2%, 0.1% typ.
Modulation frequency range	
(<3 dB) Standard Wide	DC to 100 kHz 10 Hz to 500 kHz
Incidental AM (at AF = 1 kHz, f > 10 MHz, 40 kHz deviation)	<0.1%
Stereo modulation at 40 kHz useful deviation, AF = 1 kHz, RF = 87 MHz to 108 MHz Crosstalk S/N ratio unweighted, rms S/N ratio weighted, rms Distortion	>50 dB >70 dB >70 dB <0.2%, 0.1% typ.

Carrier frequency offset at FM DC	0.1% typ. of set deviation
Modulation input EXT Input impedance	>100 kΩ
Input voltage V _p for set deviation (nominal value)	1 V
Phase modulation	
Operating modes	internal, external AC/DC,
1 0	internal/external two-tone
Phase deviation ¹¹⁾ 9 kHz to 76 MHz > 76 MHz to 151.3125 MHz > 151.3125 MHz to 302.625 MHz > 302.625 MHz to 605.25 MHz > 605.25 MHz to 1.2105 GHz > 1.2105 GHz to 1.818 GHz > 1.818 GHz to 2.655 GHz > 2.655 GHz to 3.300 GHz	0 rad to 10 (2) rad 0 rad to 1.25 (0.25) rad 0 rad to 2.5 (0.5) rad 0 rad to 5 (1) rad 0 rad to 10 (2) rad 0 rad to 20 (4) rad 0 rad to 30 (6) rad 0 rad to 40 (8) rad
Resolution	<1%, min. 0.001 rad
Setting accuracy at AF = 1 kHz	<4% of reading + 0.02 rad
Phase distortion (at AF $= 1$ kHz and 50% of maximum deviation)	<0.2%, 0.1% typ.
Modulation frequency range (–3 dB) Standard Wide	DC to 100 kHz 10 Hz to 500 kHz
Modulation inputs EXT Input impedance Input voltage V _p for set deviation (nominal value)	>100 kΩ
Pulse modulation (with option R	* *
Operating modes	internal, external
On/off ratio	>80 dB
Rise/fall time (10%/90%)	<20 ns, 10 ns typ.
Pulse repetition frequency	0 Hz to 2.5 MHz
Pulse delay	50 ns typ.
Video crosstalk (V _p)	<30 mV
Modulation input PULSE Input level Input impedance	TTL level (HCT) $10\text{k}\Omega\text{ or }50\Omega\text{, selectable with internal link}$
Pulse generator (with option R&	S SML-B3)
Operating modes	automatic, externally triggered, external gate mode, single pulse, double pulse, delayed pulse (externally triggered)
Active trigger edge	positive or negative
Pulse period Resolution Accuracy	100 ns to 85 s 5 digits, min. 20 ns <1 x 10 ⁻⁴
Pulse width Resolution Accuracy	20 ns to 1 s 4 digits, min. 20 ns <1 x 10 ⁻⁴ + 3 ns
Pulse delay Resolution Accuracy	20 ns to 1 s 4 digits, min. 20 ns <1 x 10 ⁻⁴ + 3 ns
Double-pulse spacing Resolution Accuracy	20 ns to 1 s 4 digits, min. 20 ns <1 x 10 ⁻⁴ + 3 ns
Trigger delay	50 ns typ.
Jitter	<10 ns
PULSE/VIDEO output	TTL signal ($R_L \ge 50 \Omega$)

Sweep	digital in discrete steps
RF sweep, AF sweep Operating modes Sweep range Step width (lin) Step width (log)	automatic, single-shot, manually or exter- nally triggered, linear or logarithmic user-selectable user-selectable 0.01% to 100%
Level sweep Operating modes Sweep range Step width (log)	automatic, single-shot, manually or externally triggered, logarithmic user-selectable user-selectable
Step time Resolution	10 ms to 1 s 0.1 ms
Trigger input Input level Input impedance	TTL (HCT) 10 k Ω (pull-up)
Memory for device settings	
Number of storable settings	100
Remote control	

IEC 60625 (IEEE 488) and RS-232-C

SH1, AH1, T6, L4, SR1, RL1, PP1, DC1,

Amphenol, 24-pin and 9-pin

SCPI 1995.0

0 to 30

DT1, CO

General data

System

Command set

IEC/IEEE bus address

Interface functions

Connector

Rated temperature range	0°C to 55°C; meets IEC 68-2-1 and IEC 68-2-2	
Storage temperature range	-40°C to +70°C	
Climatic resistance Damp heat	95% relative humidity at +25°C/ +40°C cyclically; meets IEC 60068	
Mechanical resistance Vibration, sinusoidal Vibration, random	5 Hz to 150 Hz, max. 2 g at 55 Hz, max. 0.5 g between 55 Hz and 150 Hz, meets IEC 60068, IEC 61010 and MILT-28800D, class 5 10 Hz to 300 Hz, acceleration 1.2 g (rms)	
Shock	40 g shock spectrum, meets MIL-STD-810D and MIL-T-28800D, class 3/5	

Electromagnetic compatibility	meets EN 55011 and EN 61326-1 (EMC directive of EU)
Immunity to radiated interference	10 V/m
Power supply	100 V to 120 V (AC), 50 Hz to 400 Hz, 200 V to 240 V (AC), 50 Hz to 60 Hz, autoranging, max. 250 VA
Safety	meets DIN EN 61010-1, IEC 1010-1, UL 3111-1, CSA 22.2 No. 1010-1
Dimensions (W x H x D)	427 mm x 88 mm x 450 mm
Weight	9.5 kg when fully equipped

- With option R&S SML-B3 only for f > 20 MHz.
- 2) With attenuator mode auto.
- 3) Temperature range 20 °C to 30 °C.
- $^{4)}$ -140 dBm to 11 dBm at f \leq 5 MHz, f >3 GHz.
- 5) With attenuator mode fixed.
- 6) After 1 hour warmup and recalibration within 4 hours of operation after temperature variations <5 °C.</p>
- 7) The modulation bandwidth continuously decreases upon approaching 5 MHz or. 3.3 GHz.
- 8) With attenuator mode auto, f≥100 kHz.
- ⁹⁾ +5 dBm to +11 dBm at f≤5 MHz, f >3 GHz.
- With option R&S SML-B3 only for f >10 MHz.
- Values in brackets apply to wide modulation bandwidth.

Ordering information

Vector Signal Generator	R&S SMV03	1147.7509.13
Accessories supplied		power cable, user manual
Options Reference Oscillator OCXO Pulse Modulator Stereo /RDS Coder Rear Connectors for AF, RF	R&S SML-B1 R&S SML-B3 R&S SML-B5 R&S SML-B19	1090.5790.02 1090.5403.02 ¹⁾ 1147.8805.02 1090.5303.02 ¹⁾
Recommended extras Service Kit 19" Rack Adapter Transport Bag Service Manual, Modules	R&S SML-Z2 R&S ZZA-211 R&S ZZT-214	1090.5203.02 1096.3260.00 1109.5119.00 1090.3123.24

1) Factory-fitted only.



